MSKSEMI 美森科













ESD

100

TSS

MOV

GDT

PLED

BAS70W/-04/-05/-06

Product specification

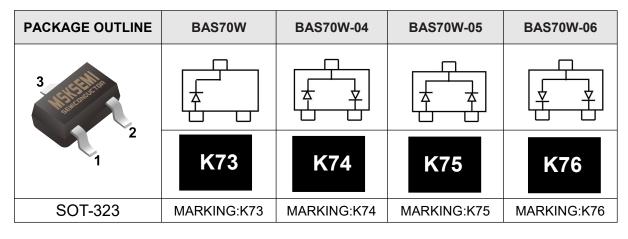


MSKSEMI

FEATURES

- Low turn-on voltage
- Fast switching
- Also available in lead free version

Reference News



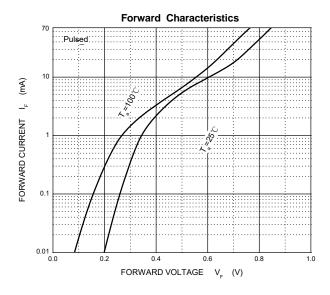
Maximum Ratings @Ta=25℃

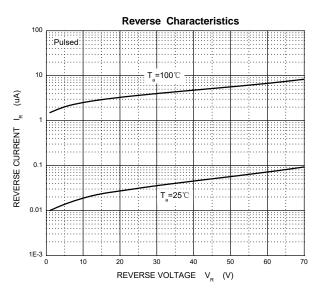
Symbol	Parameter	Value	Unit
V _R	DC Voltage	70	V
lF	Forward Continuous Current	70	mA
I _{FSM}	Non-Repetitive Peak Forward Surge Current @ t = 8.3ms	100	mA
PD	Power Dissipation	200	mW
Reja	Thermal Resistance from Junction to Ambient	500	°C/W
TJ	Operating Junction Temperature Range	-40 ~ +125	°C
T _{stg}	Storage Temperature Range	-55 ~ +150	°C

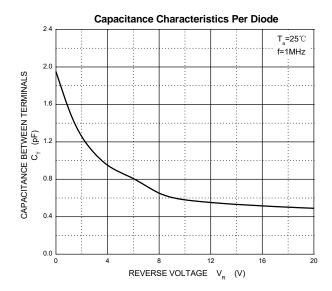
ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

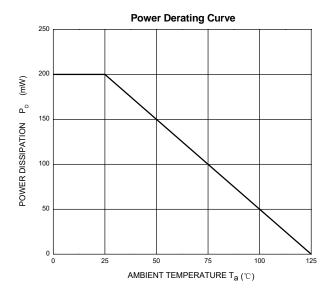
Parameter	Symbol	Test conditions	Min	Мах	Unit
Reverse breakdown voltage	V _(BR)	I _R = 10µA	70		V
Reverse voltage leakage current	ĪR	V _R =50V		100	nA
Forward voltage	VF	l⊧=1mA l⊧=15mA		410 1000	mV
Diode capacitance	CD	V _R =0V,f=1MHz		2	pF
Reveres recovery time	trr	l⊧=I _R =10mA,I _{rr} =0.1xI _R , R∟=100Ω		5	ns





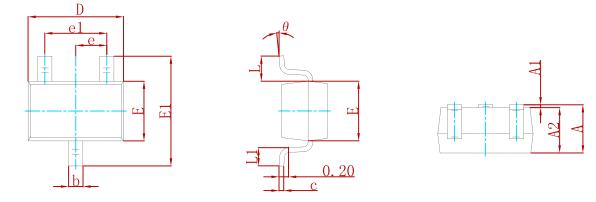






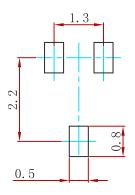


PACKAGEMECHANICALDATA



Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	0.900	1.100	0.035	0.043	
A1	0.000	0.100	0.000	0.004	
A2	0.900	1.000	0.035	0.039	
b	0.200	0.400	0.008	0.016	
С	0.080	0.150	0.003	0.006	
D	2.000	2.200	0.079	0.087	
E	1.150	1.350	0.045	0.053	
E1	2.150	2.450	0.085	0.096	
е	0.650 TYP		0.026 TYP		
e1	1.200	1.400	0.047	0.055	
L	0.525 REF		0.021 REF		
L1	0.260	0.460	0.010	0.018	
θ	0°	8°	0°	8°	

Suggested Pad Layout



Note:

1.Controlling dimension:in millimeters.

- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

REEL SPECIFICATION

P/N	PKG	QTY	
BAS70W/-04/-05/-06	SOT-323	3000	



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